

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	856	(oxygen or "O.sub.2") with (fluoro\$1silicon or SiF or "SiF.sub. 4")	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 09:59
L2	91	1 and (power near3 (density or flux))	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 10:30
L3	81	2 and @ay<='2002"	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 10:00
L4	197	(power near3 (density or flux)) same poly\$1silicon	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 10:30
L5	171	4 and @ay<="2002"	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 10:30
L6	97	5 and (oxygen or "O.sub.2" or "SF.sub.6" or "SiF.sub.4" or fluorocarbon)	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 10:31
L7	44	6 and RF	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 13:23
L8	1289	438/710.ccls.	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 13:24
L9	216	438/711.ccls.	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 13:24
L10	2920	438/714.ccls.	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 13:24
L11	640	438/719.ccls.	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 13:25
L12	49	438/728.ccls.	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 13:25
L13	223	438/729.ccls.	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 13:27
L14	43	Mimura-Takanori.in.	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 13:27
L15	100	Nagaseki-Kazuya.in.	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 13:27

L16	2083	Yamamoto-Kenji.in.	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 13:28
L17	3	Huang-Yahui.in.	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 13:28
S1	854	(oxygen or "O.sub.2") with (fluoro\$1silicon or SiF or "SiF.sub. 4")	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/06 09:59
S2	774	S1 and (silicon or SiO or "SiO.sub. 2" or poly\$1silicon)	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/04 15:44
S3	366	S2 and RF	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/09/29 16:21
S4	309	S3 and @ay<="2002"	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/09/29 16:21
S5	198	S4 and ("CF.sub.4" or fluoro\$1carbon or fluoro\$1sulfur or SF6 or "SF.sub.6" or hexa\$1fluoride)	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/03 11:05
S6	854	(oxygen or "O.sub.2") with (fluoro\$1silicon or SiF or "SiF.sub. 4")	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/03 11:05
S7	689095	"2" and (silicon or SiO or "SiO.sub. 2" or poly\$1silicon)	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/03 11:05
S8	774	S6 and (silicon or SiO or "SiO.sub. 2" or poly\$1silicon)	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/03 16:35
S9	198	S8 and ("CF.sub.4" or fluoro\$1carbon or fluoro\$1sulfur or SF6 or "SF.sub.6" or hexa\$1fluoride) and RF and @ay<="2002"	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/03 11:06
S10	5	S8 and Mz	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/03 16:35
S11	312	S8 and Mhz	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/03 17:23
S12	273	S11 and @ay<="2002"	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/03 16:35
S13	273	S12 and (silicon or SiO or "SiO. sub.2" or poly\$1silicon)	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/03 16:36

S14	134	S13 not S9	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/03 16:36
S15	122	S8 and GHz	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/03 17:23
S16	103	S15 not S14	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/03 17:23
S17	96	S16 and @ay<="2003"	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/03 17:24
S18	79	S16 and @ay<="2002" and (etch or etching)	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/03 17:24
S19	1	"5272417".pn.	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/04 14:28
S20	81	("5272417").URPN.	USPAT	OR	ON	2005/10/04 14:30
S21	46	S20 and (MHz or GHz)	USPAT	OR	ON	2005/10/04 14:30
S22	42	S21 and @ay<="2001"	USPAT	OR	ON	2005/10/04 14:30
S23	46	S21 and @ay<="2002"	USPAT	OR	ON	2005/10/04 15:43
S24	5543	(etch or etching) and RF and magnetic	USPAT	OR	ON	2005/10/04 17:02
S25	2826	S24 and (oxygen or "O.sub.2")	USPAT	OR	ON	2005/10/04 17:01
S26	1505	S25 and (MHz or GHz)	USPAT	OR	ON	2005/10/04 15:44
S27	383	S26 and (magnetic with (gauss or G!))	USPAT	OR	ON	2005/10/04 15:44
S28	373	S27 and @ay<="2002"	USPAT	OR	ON	2005/10/04 15:44
S29	354	S28 and (silicon or SiO or "SiO.sub.2" or poly\$1silicon)	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/04 15:44
S30	141	S29 and (fluoro\$1silicon or SiF or "SiF.sub.4" or "SF.sub.6" or hexa\$1fluoride)	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/04 15:47
S31	42	S30 and trench	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/04 16:48
S32	36	(etch or etching) and ("3.2" adj MHz)	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/04 16:48
S33	570	S25 and (RF with (flux or density))	USPAT	OR	ON	2005/10/04 17:02
S34	185	S33 and trench	USPAT	OR	ON	2005/10/04 17:02
S35	8951	(etch or etching) and RF and magnetic	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/04 17:02

S36	1456	S35 and (RF with (flux or density))	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/04 17:07
S37	314	S36 and trench and (oxygen or "O sub.2")	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/04 17:03
S38	243	S37 and @ay<="2002"	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/04 17:03
S39	209	S38 and temperature	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/04 17:03
S40	752	S35 and (RF near4(flux or density))	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/04 17:07
S41	154	S40 and trench and @ay<="2002" and temperature	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/10/04 17:08